Pb Free Plating Product

ES5A thru ES5J

5.0 Ampere Surface Mount Type Super Fast Recovery Rectifier Diodes

FEATURE

- Glass passivated chip junction
- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Low reverse leakage
- Built-in strain relief,ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 250°C/10 seconds at terminals

MECHANICAL DATA

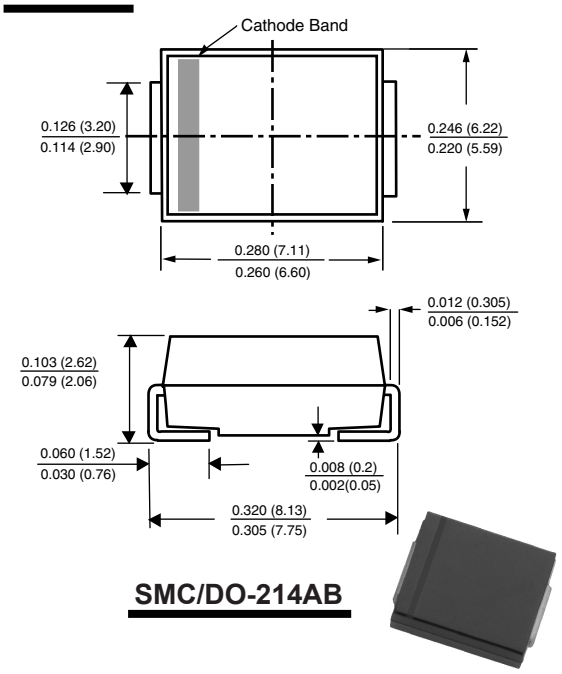
Case:SMC/DO-214AB Package
Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode band
Mounting Position: Any
Weight: 0.22 gram approximately

APPLICATION

- LED SMPS/Industrial power supply
- HID ballast stabilizer
- Telecommunication SMPS/LED street lamp

OUTLINE

Unit:inch(millimeter)



SMC/DO-214AB

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

	SYMBOLS	ES5A	ES5B	ES5C	ES5D	ES5E	ES5G	ES5J	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	300	400	600	VOLTS
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	420	VOLTS
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	600	VOLTS
Maximum average forward rectified current at T_L=75°C	$I_{(AV)}$	5.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150.0							Amps
Maximum instantaneous forward voltage at 5.0A	V_F	0.95				1.3		1.7	Volts
Maximum DC reverse current T_A=25°C at rated DC blocking voltage T_A=100°C	I_R	10.0 300.0							μA
Maximum reverse recovery time (NOTE 1)	t_{rr}	35							ns
Typical junction capacitance (NOTE 2)	C_J	58.0							pF
Typical thermal resistance	$R_{\theta JA}$	47.0							°C/W
Operating junction and storage temperature range	T_J,T_{STG}	-65 to +150							°C

Note:1.Reverse recovery condition I_F=0.5A,I_R=1.0A,Irr=0.25A

2.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

© 2006 Thinki Semiconductor Co.,Ltd.

RATINGS AND CHARACTERISTIC CURVES ES5A thru ES5J

FIG. 1- FORWARD CURRENT DERATING CURVE

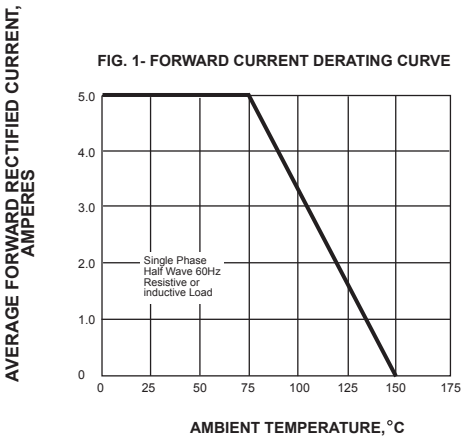


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

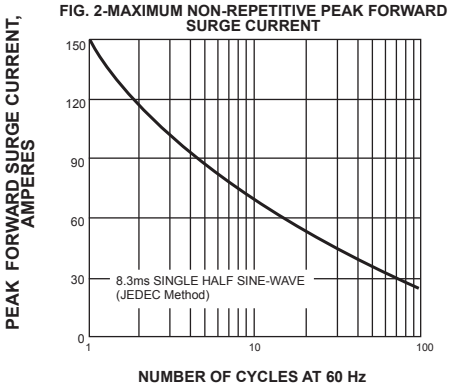


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

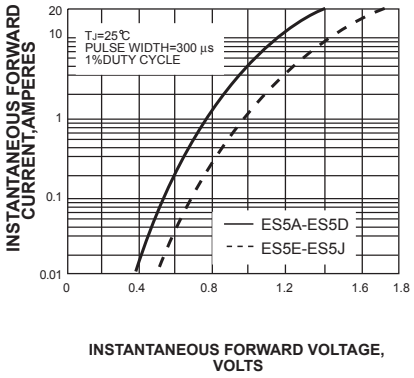


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

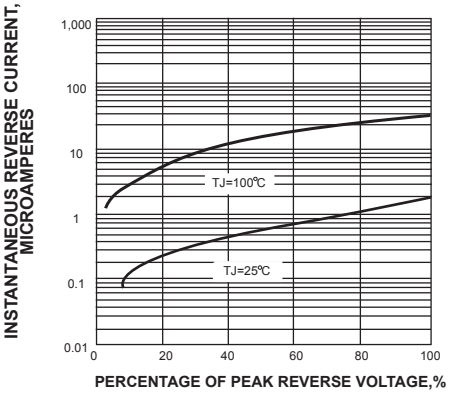


FIG. 5-TYPICAL JUNCTION CAPACITANCE

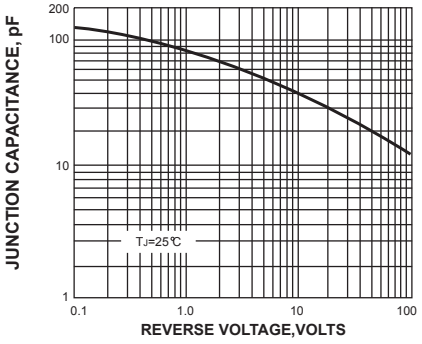
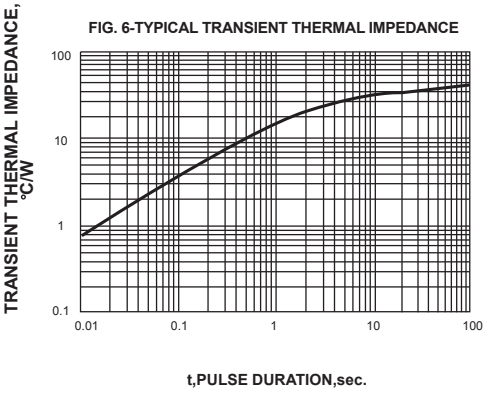


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



© 2006 Thinki Semiconductor Co.,Ltd.